## NSN 5961-01-039-8730

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Inclosure Material:
Metal
Overall Length:
0.460 inches
Overall Height:
0.460 inches
Overall Diameter:
0.687 inches
End Application:
Arts2a, automated radar terminal system 2a, dtfa01-90c-00057
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.250 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
170.0 breakdown voltage, collector-to-base, emitter open
Current Rating Per Characteristic:
15.00 amperes source cutoff current
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector absolute
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No

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